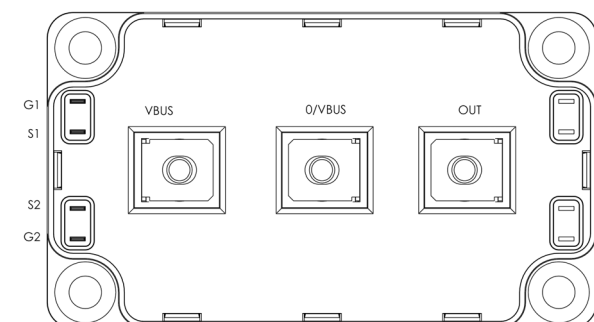
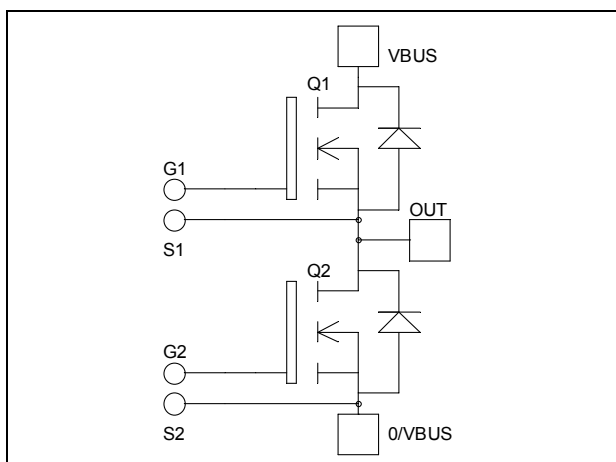


## Phase leg MOSFET Power Module

 $V_{DSS} = 1200V$ 
 $R_{DSon} = 150m\Omega \text{ typ @ } T_j = 25^\circ C$ 
 $I_D = 60A \text{ @ } T_c = 25^\circ C$ 


### Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

### Features

- Power MOS 7<sup>®</sup> FREDFETs
  - Low  $R_{DSon}$
  - Low input and Miller capacitance
  - Low gate charge
  - Fast intrinsic reverse diode
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
$V_{DSS}$	Drain - Source Breakdown Voltage	1200	V
$I_D$	Continuous Drain Current	$T_c = 25^\circ C$ 60 $T_c = 80^\circ C$ 45	A
$I_{DM}$	Pulsed Drain current	240	
$V_{GS}$	Gate - Source Voltage	$\pm 30$	V
$R_{DSon}$	Drain - Source ON Resistance	175	m $\Omega$
$P_D$	Maximum Power Dissipation	$T_c = 25^\circ C$ 1250	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)	22	A
$E_{AR}$	Repetitive Avalanche Energy	50	mJ
$E_{AS}$	Single Pulse Avalanche Energy	3000	

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

**All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified**

### Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1200V$			500	$\mu A$
		$V_{GS} = 0V, V_{DS} = 1000V$			3000	
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 30A$		150	175	$m\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 10mA$	3		5	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30V, V_{DS} = 0V$			$\pm 250$	nA

### Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$ $V_{DS} = 25V$ $f = 1MHz$		20.6		nF
$C_{oss}$	Output Capacitance			3.08		
$C_{rss}$	Reverse Transfer Capacitance			0.52		
$Q_g$	Total gate Charge	$V_{GS} = 10V$ $V_{Bus} = 600V$ $I_D = 60A$		748		nC
$Q_{gs}$	Gate – Source Charge			96		
$Q_{gd}$	Gate – Drain Charge			480		
$T_{d(on)}$	Turn-on Delay Time	<b>Inductive switching @ <math>125^\circ\text{C}</math></b> $V_{GS} = 15V$ $V_{Bus} = 800V$ $I_D = 60A$ $R_G = 1.2\Omega$		20		ns
$T_r$	Rise Time			15		
$T_{d(off)}$	Turn-off Delay Time			160		
$T_f$	Fall Time			45		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ <math>25^\circ\text{C}</math></b> $V_{GS} = 15V, V_{Bus} = 800V$ $I_D = 60A, R_G = 1.2\Omega$		3.96		mJ
$E_{off}$	Turn-off Switching Energy			2.74		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ <math>125^\circ\text{C}</math></b> $V_{GS} = 15V, V_{Bus} = 800V$ $I_D = 60A, R_G = 1.2\Omega$		6.26		mJ
$E_{off}$	Turn-off Switching Energy			3.43		

### Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I <sub>S</sub>	Continuous Source current (Body diode)		T <sub>C</sub> = 25°C			60	A
			T <sub>C</sub> = 80°C			45	
V <sub>SD</sub>	Diode Forward Voltage	V <sub>GS</sub> = 0V, I <sub>S</sub> = - 60A				1.3	V
dv/dt	Peak Diode Recovery ❶					18	V/ns
t <sub>rr</sub>	Reverse Recovery Time	I <sub>S</sub> = - 60A V <sub>R</sub> = 600V di <sub>S</sub> /dt = 400A/μs	T <sub>j</sub> = 25°C			320	ns
			T <sub>j</sub> = 125°C			650	
Q <sub>rr</sub>	Reverse Recovery Charge		T <sub>j</sub> = 25°C		8		μC
			T <sub>j</sub> = 125°C		28		

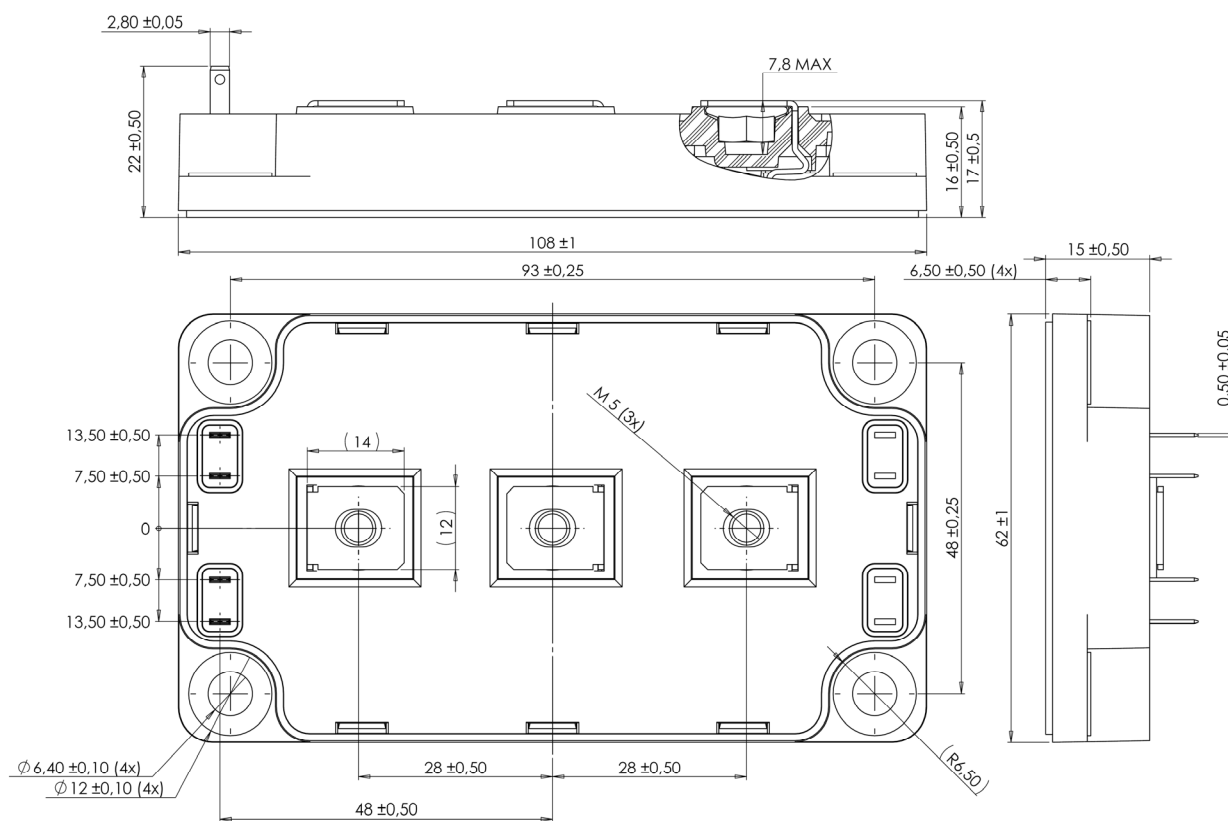
❶  $dv/dt$  numbers reflect the limitations of the circuit rather than the device itself.

$I_S \leq -60A$      $di/dt \leq 700A/\mu s$      $V_R \leq V_{DSS}$      $T_j \leq 150^\circ\text{C}$

## Thermal and package characteristics

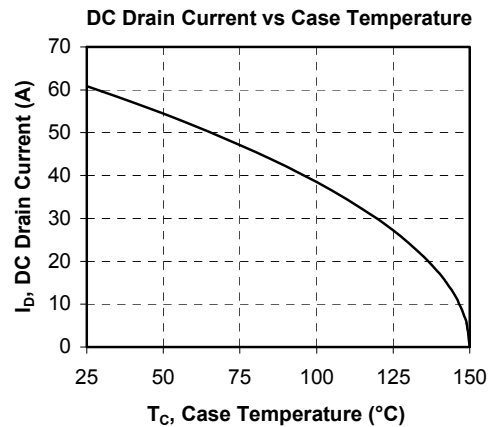
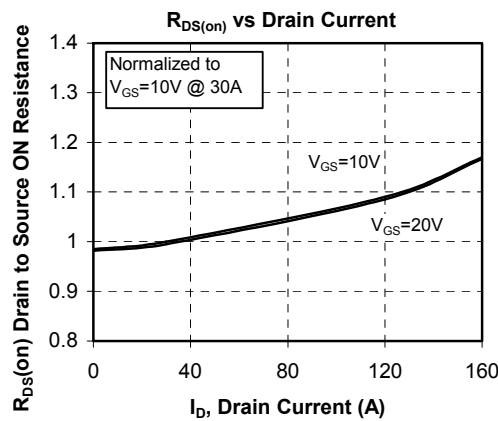
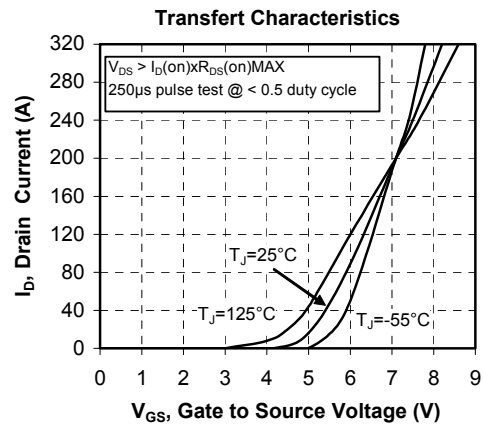
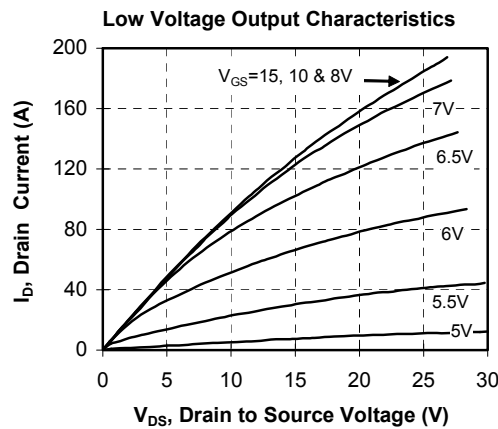
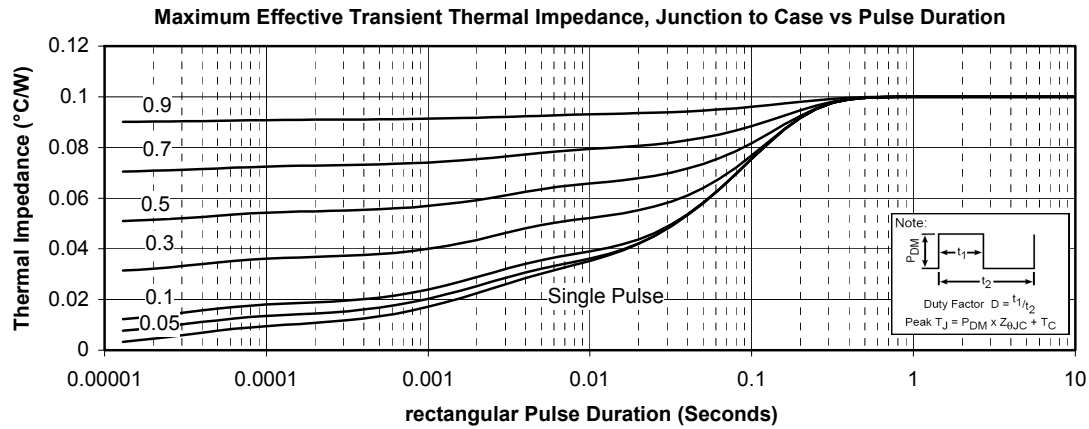
<i>Symbol</i>	<i>Characteristic</i>	<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
R <sub>thJC</sub>	Junction to Case Thermal Resistance			0.1	°C/W
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz	4000			V
T <sub>J</sub>	Operating junction temperature range	-40		150	°C
T <sub>STG</sub>	Storage Temperature Range	-40		125	
T <sub>C</sub>	Operating Case Temperature	-40		100	
Torque	Mounting torque	To heatsink	M6	3	N.m
		For terminals	M5	2	
Wt	Package Weight			300	g

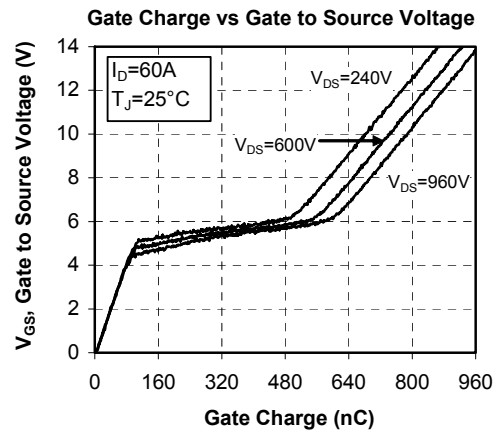
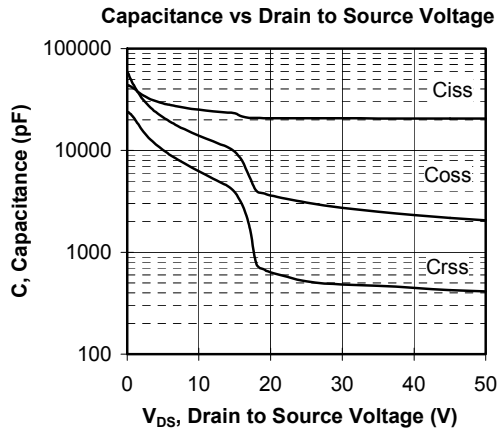
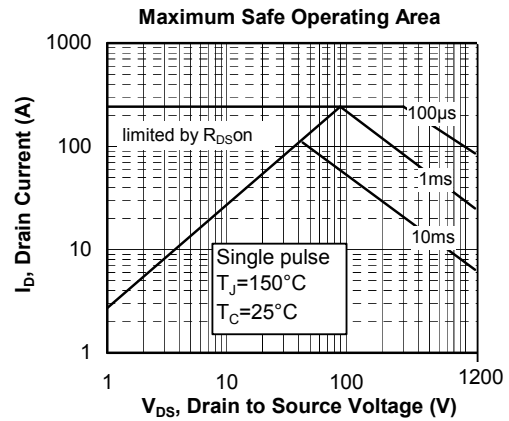
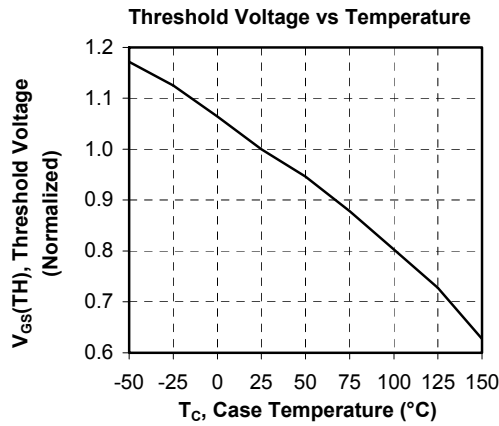
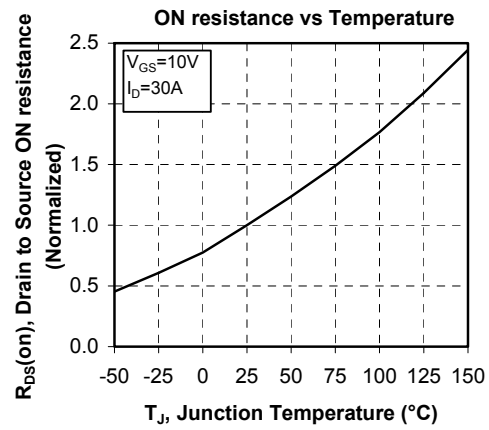
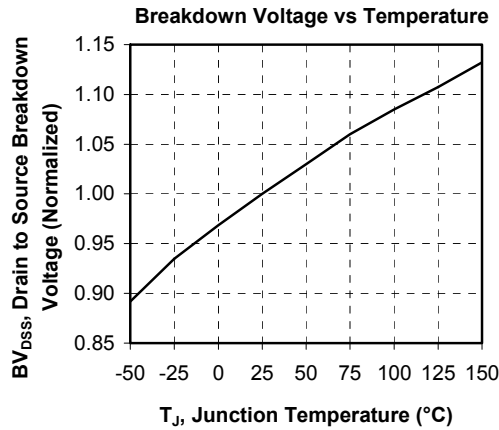
### SP6 Package outline (dimensions in mm)

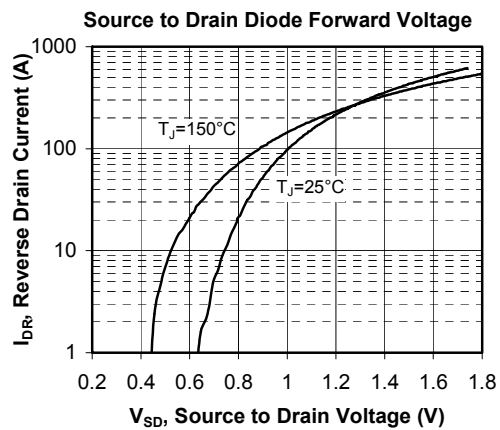
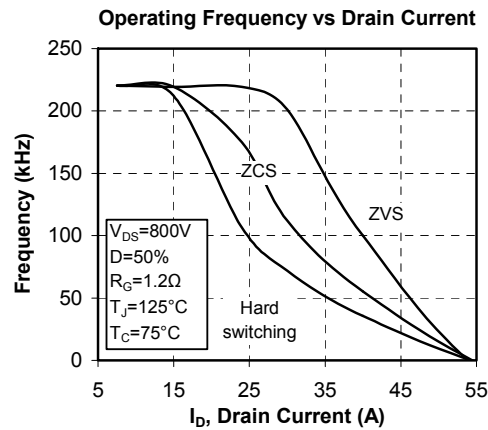
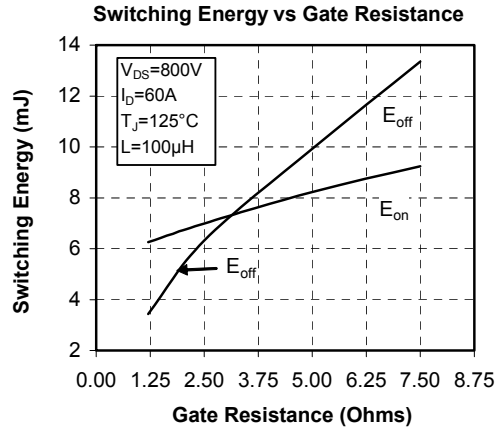
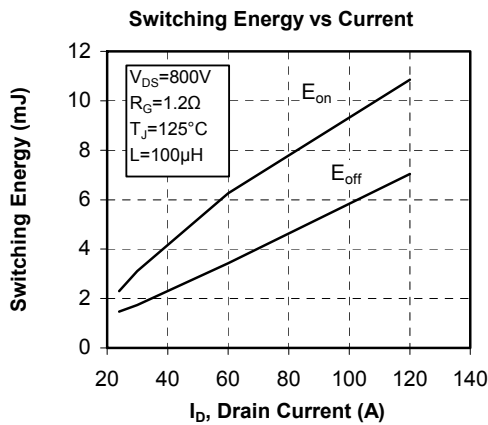
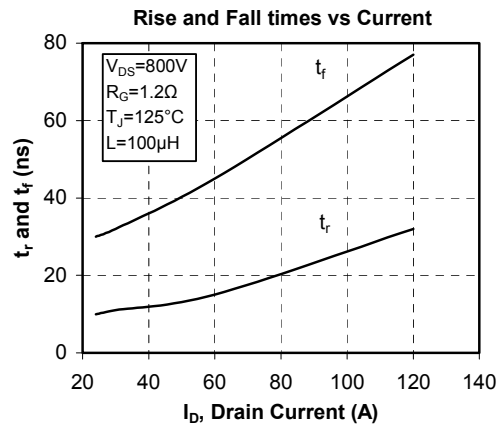
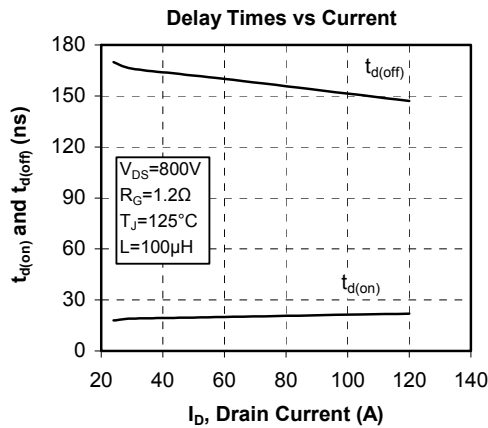


See application note APT0601 - Mounting Instructions for SP6 Power Modules on [www.microsemi.com](http://www.microsemi.com)

## Typical Performance Curve







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